Features

- EE Programmable 262,144 x 1-, 524,288 x 1-, 1,048,576 x 1-, 2,097,152 x 1-, and 4,194,304 x 1-bit Serial Memories Designed to Store Configuration Programs for Field Programmable Gate Arrays (FPGAs)
- Available as a 3.3V (±10%) Commercial and Industrial Version
- Simple Interface to SRAM FPGAs
- Pin Compatible with Xilinx[®] XC17SXXXA and XC17SXXXXL PROMs
- Compatible with Xilinx Spartan[®]-II, Spartan-IIE and Spartan XL FPGAs in Master Serial Mode
- Very Low-power CMOS EEPROM Process
- Available in 8-lead PDIP, 8-lead SOIC, 20-lead SOIC and 44-lead TQFP Packages for a Specific Density
- Low-power Standby Mode
- High-reliability
 - Endurance: Minimum 10 Write Cycles
 - Data Retention: 20 Years at 85°C

Description

The AT17N series FPGA Configuration EEPROM (Configurators) provide an easy-touse, cost-effective configuration memory for Field Programmable Gate Arrays. The AT17N series device is packaged in the 8-lead PDIP, 8-lead SOIC, 20-lead SOIC and 44-lead TQFP, see Table 1. The AT17N series Configurators uses a simple serialaccess procedure to configure one or more FPGA devices.

The AT17N series configurators can be programmed with industry-standard programmers, Atmel's ATDH2200E Programming Kit or Atmel's ATDH2225 ISP Cable and factory programming.

5							
Package	AT17N256	AT17N512/ AT17N010	AT17N002	AT17N040			
8-lead PDIP	Yes	Yes	-	-			
8-lead SOIC	Yes	_	_	_			
20-lead SOIC	Yes	Yes	Yes	_			
44-lead TQFP	_	_	Yes	Yes			

Table 1. AT17N Series Packages



FPGA Configuration Memory

AT17N256 AT17N512 AT17N010 AT17N002 AT17N040

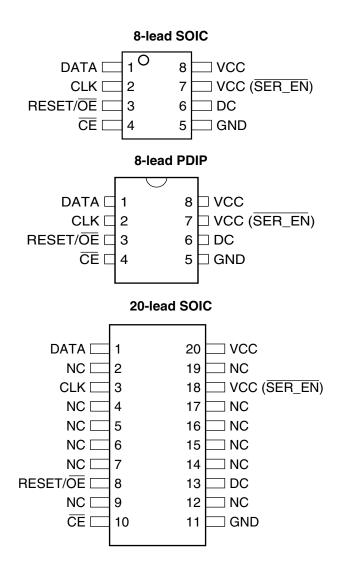
3.3V System Support

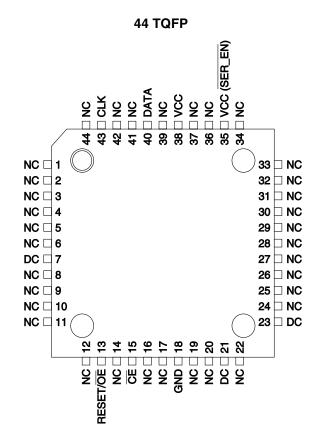






Pin Configuration

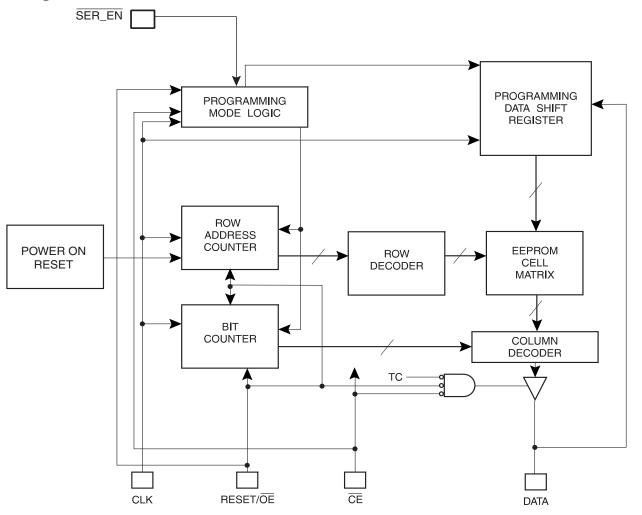








Block Diagram



Device Description

The control signals for the configuration EEPROM (\overline{CE} , RESET/ \overline{OE} and CCLK) interface directly with the FPGA device control signals. All FPGA devices can control the entire configuration process and retrieve data from the configuration EEPROM without requiring an external intelligent controller.

The configuration EEPROM RESET/ \overline{OE} and \overline{CE} pins control the tri-state buffer on the DATA output pin and enable the address counter. When RESET/ \overline{OE} is driven High, the configuration EEPROM resets its address counter and tri-states its DATA pin. The \overline{CE} pin also controls the output of the AT17N series configurator. If \overline{CE} is held High after the RESET/ \overline{OE} reset pulse, the counter is disabled and the DATA output pin is tri-stated. When \overline{OE} is subsequently driven Low, the counter and the DATA output pin are enabled. When RESET/ \overline{OE} is driven High again, the address counter is reset and the DATA output pin is tri-stated, regardless of the state of \overline{CE} . Upon power-up, the address counter is automatically reset.

AT17N002

AT17N040

Name	I/O	8 DIP/ SOIC	20 SOIC	8 DIP	20 SOIC	20 SOIC	44 TQFP	44 TQFP
DATA	I/O	1	1	1	1	1	40	40
CLK	I	2	3	2	3	3	43	43
RESET/OE	Ι	3	8	3	8	8	13	13
CE	I	4	10	4	10	10	15	15
GND		5	11	5	11	11	18	18
DC	0	6	13	6	13	13	21	21
DC	0	_	_	_	-	_	23	23
VCC(SER_EN)	Ι	7	18	7	18	18	35	35
V _{CC}		8	20	8	20	20	38	38
		prog	gramming.				bit counter for	-
RESET/OE		leve Low eith	Output Enable (active High) and RESET (active Low) when SER_EN is High. A Lo level on RESET/OE resets both the address and bit counters. A High level (with C Low) enables the data output driver. The logic polarity of this input is programmable a either RESET/OE or RESET/OE. For most applications, RESET should be programme active Low. This document describes the pin as RESET/OE.					
CE		add the Note	Chip Enable input (active Low). A Low level (with OE High) allows CLK to increment the address counter and enables the data output driver. A High level on \overline{CE} disables both the address and bit counters and forces the device into a low-power standby mode. Note that this pin will <i>not</i> enable/disable the device in the Two-Wire Serial Programming mode (SER_EN Low).					
GND		Gro	Ground pin. A 0.2 μF decoupling capacitor between V_{CC} and GND is recommended.					
VCC(SER_EN))	Low	Serial enable must be held High during FPGA loading operations. Bringing $\overline{\text{SER}}_{\text{E}}$ Low enables the Two-Wire Serial Programming Mode. For non-ISP applications SER_EN should be tied to V _{CC} .					
V _{cc}		3.3\	/ (±10%) Com	mercial and Ir	ndustrial powe	r supply pin.		

AT17N512/

AT17N010

Pin Description

AT17N256

NC pins are No Connect pins, which are not internally bonded out to the die.

DC DC pins are No Connect pins internally connected to the die. It is not recommended to connect these pins to any external signal.



NC



FPGA Master Serial Mode Summary	The I/O and logic functions of any SRAM-based FPGA are established by a configura- tion program. The program is loaded either automatically upon power-up, or on command, depending on the state of the FPGA mode pins. In Master mode, the FPGA automatically loads the configuration program from an external memory. The AT17N Serial Configuration EEPROM has been designed for compatibility with the Master Serial mode.
	This document discusses the master serial mode configuration of Atmel AT17N series configuration memories, pin compatible with Spartan-II, Spartan-IIE and Spartan XL OTP PROMs.
Control of Configuration	 Most connections between the FPGA device and the AT17N Serial EEPROM are simple and self-explanatory. The DATA output of the AT17N series configurator drives DIN of the FPGA devices. The master FPGA CCLK output drives the CLK input of the AT17N series configurator. SER_EN must be connected to V_{CC} (except during ISP). The CE and OE/Reset are driven by the FPGA to enable output data buffer of the EEPROM.
Programming Mode	The programming mode is entered by bringing $\overline{\text{SER}_{EN}}$ Low. In this mode the chip can be programmed by the Two-Wire serial bus. The programming is done at V _{CC} supply only. Programming super voltages are generated inside the chip.
Standby Mode	The AT17N series configurators enter a low-power standby mode whenever \overline{CE} is asserted High. In this mode, the AT17N256 configurator consumes less than 50 µA of current at 3.3V (100 µA for the AT17N512/010 and 200 µA for the AT17N002/040).

AT17N256/512/010/002/040

Absolute Maximum Ratings*

Operating Temperature40°C to +85°C
Storage Temperature65 °C to +150°C
Voltage on Any Pin with Respect to Ground0.1V to V _{CC} +0.5V
Supply Voltage (V $_{\rm CC}$)
Maximum Soldering Temp. (10 sec. @ 1/16 in.)260°C
ESD (R _{ZAP} = 1.5K, C _{ZAP} = 100 pF)

*NOTICE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those listed under operating conditions is not implied. Exposure to Absolute Maximum Rating conditions for extended periods of time may affect device reliability.

Operating Conditions

			3.	3V	
Symbol	Description		Min	Max	Units
	Commercial	Supply voltage relative to GND -0°C to +70°C	3.0	3.6	V
V _{cc}	Industrial	Supply voltage relative to GND -40°C to +85°C	3.0	3.6	V





DC Characteristics

 $V_{CC}=3.3V\pm10\%$

			AT17	AT17N256		AT17N512/ AT17N010		AT17N002/ AT17N040	
Symbol	Description		Min	Max	Min	Max	Min	Max	Units
V _{IH}	High-level Input Voltage		2.0	V _{CC}	2.0	V _{CC}	2.0	V _{CC}	V
V _{IL}	Low-level Input Voltage		0	0.8	0	0.8	0	0.8	V
V _{OH}	High-level Output Voltage (I _{OH} = -2.5 mA)		2.4		2.4		2.4		v
V _{OL}	Low-level Output Voltage (I _{OL} = +3 mA)	Commercial		0.4		0.4		0.4	v
V _{OH}	High-level Output Voltage (I _{OH} = -2 mA)		2.4		2.4		2.4		v
V _{OL}	Low-level Output Voltage (I _{OL} = +3 mA)	Industrial		0.4		0.4		0.4	v
I _{CCA}	Supply Current, Active Mode			5		5		5	mA
I _L	Input or Output Leakage Current $(V_{IN} = V_{CC} \text{ or GND})$		-10	10	-10	10	-10	10	μA
		Commercial		50		100		150	μA
I _{CCS}	Supply Current, Standby Mode	Industrial		100		100		150	μA

AC Characteristics

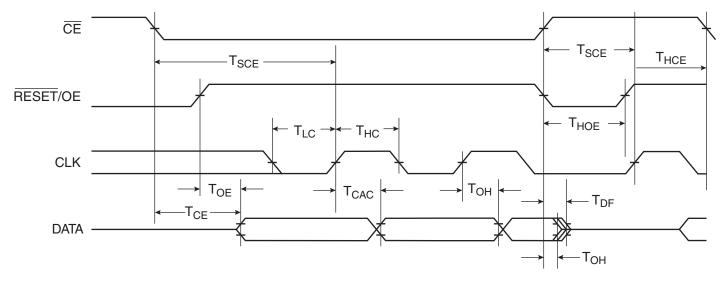
 $V_{CC} = 3.3V \pm 10\%$

		AT17N256			AT17N512/010/002/040					
		Comn	nercial	Indu	strial	Comn	nercial	Indu	strial	
Symbol	Description	Min	Max	Min	Max	Min	Max	Min	Мах	Units
T _{OE} ⁽¹⁾	OE to Data Delay		50		55		50		55	ns
T _{CE} ⁽¹⁾	CE to Data Delay		60		60		55		60	ns
T _{CAC} ⁽¹⁾	CLK to Data Delay		75		80		55		60	ns
Т _{ОН}	Data Hold from \overline{CE} , OE, or CLK	0		0		0		0		ns
T _{DF} ⁽²⁾	CE or OE to Data Float Delay		55		55		50		50	ns
T _{LC}	CLK Low Time	25		25		25		25		ns
T _{HC}	CLK High Time	25		25		25		25		ns
T _{SCE}	CE Setup Time to CLK (to guarantee proper counting)	35		60		30		35		ns
T _{HCE}	CE Hold Time from CLK (to guarantee proper counting)	0		0		0		0		ns
T _{HOE}	OE High Time (guarantees counter is reset)	25		25		25		25		ns
F _{MAX}	Maximum Clock Frequency		10		10		15		10	MHz

Notes: 1. AC test lead = 50 pF.

2. Float delays are measured with 5 pF AC loads. Transition is measured \pm 200 mV from steady-state active levels.

AC Characteristics







Thermal Resistance Coefficients⁽¹⁾

Packag	де Туре		AT17N256	AT17N512/ AT17N010	AT17N002	AT17N040
8P3	Plastic Dual Inline Package	θ _{JC} [°C/W]	37	37	_	_
(PDIP)	θ _{JA} [°C/W] ⁽²⁾	107	107	_	_	
8S1	Plastic Gull Wing Small Outline	θ _{JC} [°C/W]	45	_	_	_
	(SOIC)	θ _{JA} [°C/W] ⁽²⁾	150	-	-	-
20S2	Plastic Gull Wing Small Outline	θ _{JC} [°C/W]				_
(SOIC)		θ _{JA} [°C/W] ⁽²⁾				-
44A	44A Thin Plastic Quad Flat	θ _{JC} [°C/W]	_	_	17	17
	Package (TQFP)	$^{\theta_{JA}}$ [°C/W] ⁽²⁾	_	_	62	62

Notes: 1. For more information refer to the "Thermal Characteristics of Atmel's Packages", available on the Atmel web site. 2. Airflow = 0 ft/min.

Figure 1. Ordering Code

	AT17N	1256-10PC	
Voltage	Size (Bits)	Package	Temperature
3.3V ±10%	256 = 256K		C = Commercial
	512 = 512K	P = 8P3	I = Industrial
	010 = 1M	N = 8S1	
	002 = 2M	S = 20S2	
	040 = 4M	TQ = 44A	

	Package Type				
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)				
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)				
20S2	20-lead, 0.300" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)				
44 A	44-lead, Thin (1.0 mm) Plastic Quad Flat Package Carrier (TQFP)				





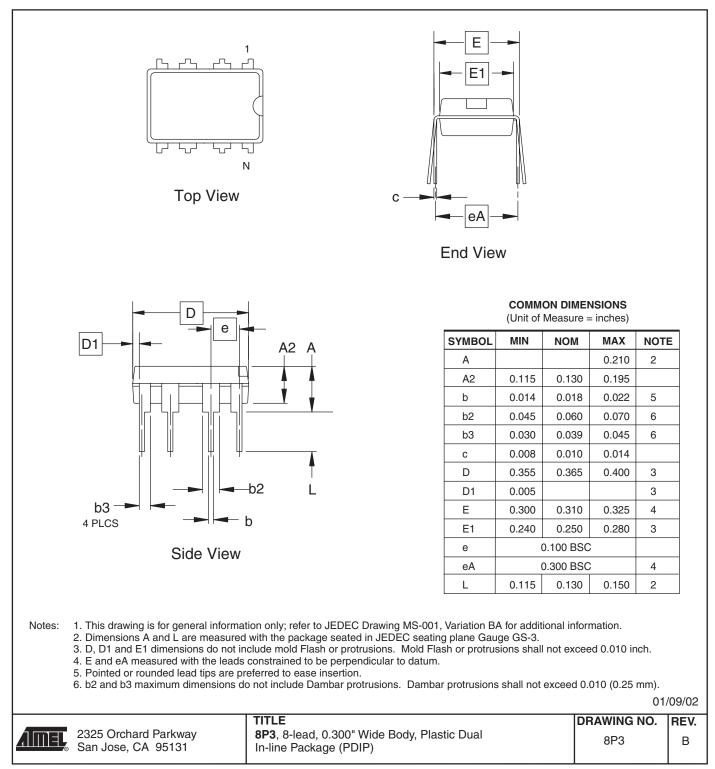
Ordering Information

Memory Size	Ordering Code	Package	Operation Range
	AT17N256-10PC	8P3	Commonsial
	AT17N256-10NC	8S1	Commercial (0°C to 70°C)
256-Kbit	AT17N256-10SC	20S2	
250-101	AT17N256-10PI	8P3	
	AT17N256-10NI	8S1	Industrial (-40°C to 85°C)
	AT17N256-10SI	20S2	(-40 0 10 03 0)
512-Kbit	AT17N512-10SC	20S2	Commercial (0°C to 70°C)
512-RDI	AT17N512-10SI	20S2	Industrial (-40°C to 85°C)
	AT17N010-10SC	20S2	Commercial (0°C to 70°C)
1-Mbit	AT17N010-10SI	20S2	Industrial (-40°C to 85°C)
	AT17N002-10SC	20S2	Commercial
	AT17N002-10TQC	44A	(0°C to 70°C)
2-Mbit	AT17N002-10SI	20S2	Industrial
	AT17N002-10TQI	44A	(-40°C to 85°C)
4-Mbit	AT17N040-10TQC	44A	Commercial (0°C to 70°C)
4-IVIUII —	AT17N040-10TQI	44A	Industrial (-40°C to 85°C)

Notes: 1. For the -10CC and -10CI packages, customers may migrate to AT17LVXXX-10CU.

Packaging Information

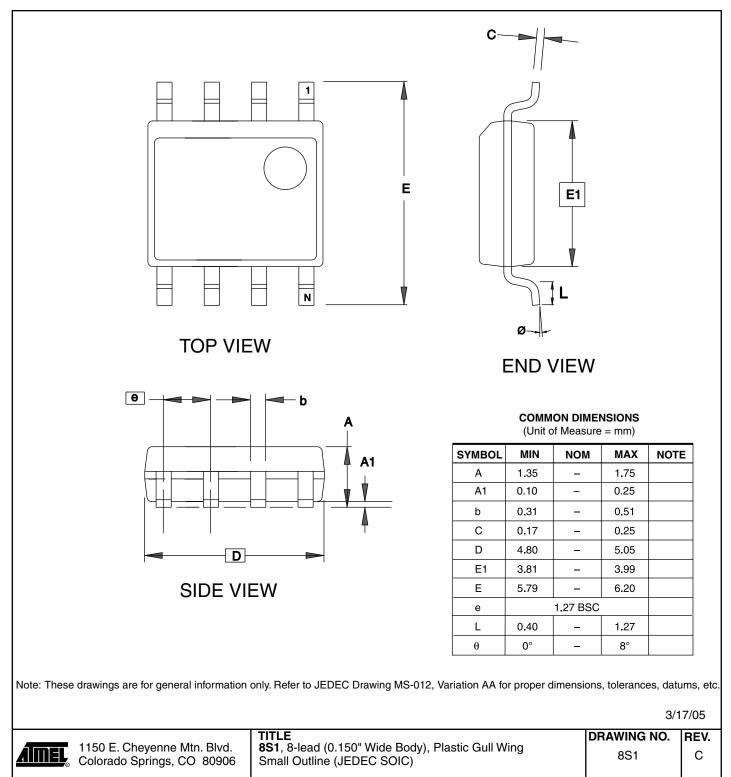








8S1 - SOIC

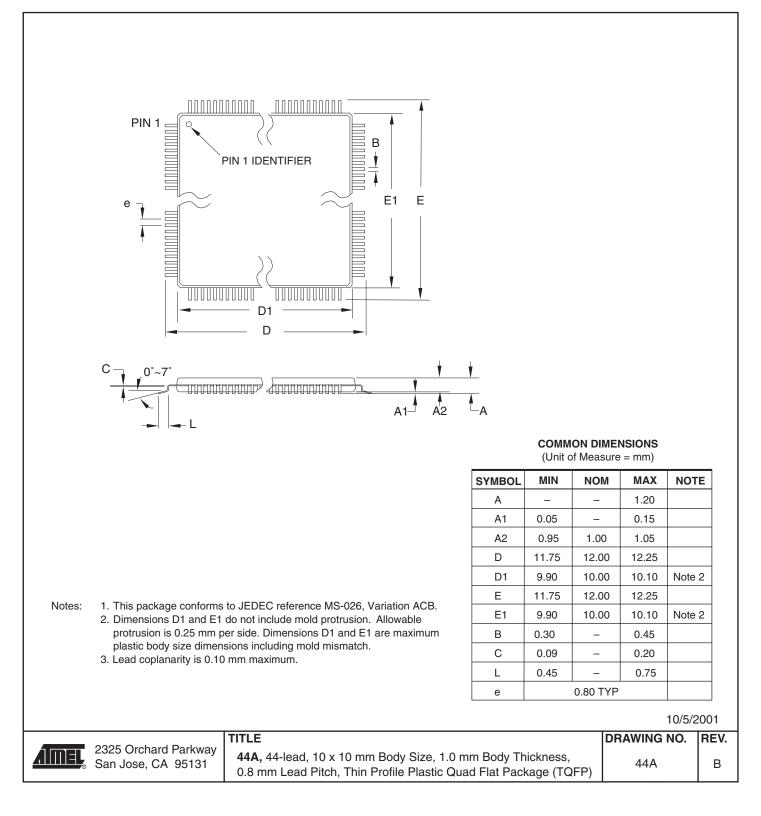


20S2 - SOIC





44A – TQFP



Revision History

Revision Level – Release Date	History		
B – March 2006	Added last-time buy for AT17NXXX-10CC and AT17NXXX-10CI.		
C – August 2007	Removed 8CN4 8-lead LAP package.		





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